



DMT10H017LPD

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>C</sub> = +25°C	
100V	17.4mΩ @ V <sub>GS</sub> = 10V	54.7A	
	$30.3m\Omega @ V_{GS} = 4.5V$	41.4A	

# **Description and Applications**

This new generation MOSFET features low on-resistance and fast switching, making it ideal for high efficiency power management applications.

- Synchronous Rectifier
- **DC-DC Converters**
- Primary Side Switching

# PowerDI5060-8

### **Features and Benefits**

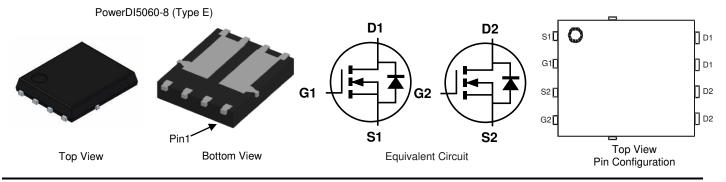
100% Unclamped Inductive Switching-Ensures More Reliable and Robust End Application

**DUAL N-CHANNEL ENHANCEMENT MODE MOSFET** 

- **High-Conversion Efficiency**
- Low RDS(ON)-Minimizes On State Losses
- Low-Input Capacitance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts gualified to AEC- Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

### **Mechanical Data**

- Case: PowerDI<sup>®</sup>5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208(e3)
- Weight: 0.097 grams (Approximate)



### Ordering Information (Note 4)

	Part Number	Case	Packaging			
	DMT10H017LPD-13	PowerDI5060-8 (Type E)	2500 / Tape & Reel			
Notes:	Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3).compliant. All applicable RoHS exemptions applied.					

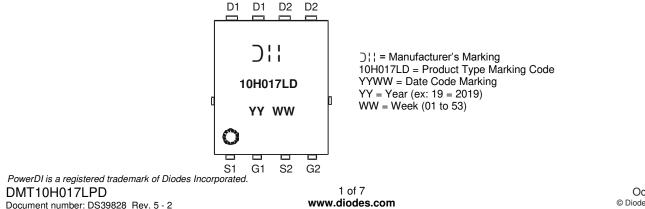
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3).compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# Marking Information





### Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		V <sub>DSS</sub>	100	V
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Continuous Drain Current, V <sub>GS</sub> = 10V (Note 6)	$T_{C} = +25^{\circ}C$ $T_{C} = +70^{\circ}C$	۱ <sub>D</sub>	54.7 43.7	А
Maximum Body Diode Forward Current (Note 6)	<u>.</u>	ls	60	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	60	А
Avalanche Current, L = 3mH (Note 8)		I <sub>AS</sub>	10	A
Avalanche Energy, L = 3mH (Note 8)		E <sub>AS</sub>	150	mJ
Avalanche Current, L = 1mH		I <sub>AS</sub>	10	A
Avalanche Energy, L = 1mH	E <sub>AS</sub>	50	mJ	

### **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation	$T_A = +25^{\circ}C$	PD	2.2	W
Thermal Resistance, Junction to Ambient (Note 5)		R <sub>ØJA</sub>	56	°C/W
Total Power Dissipation	$T_{\rm C} = +25^{\circ}{\rm C}$	PD	78	W
Thermal Resistance, Junction to Case (Note 6)		R <sub>ejc</sub>	1.6	°C/W
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

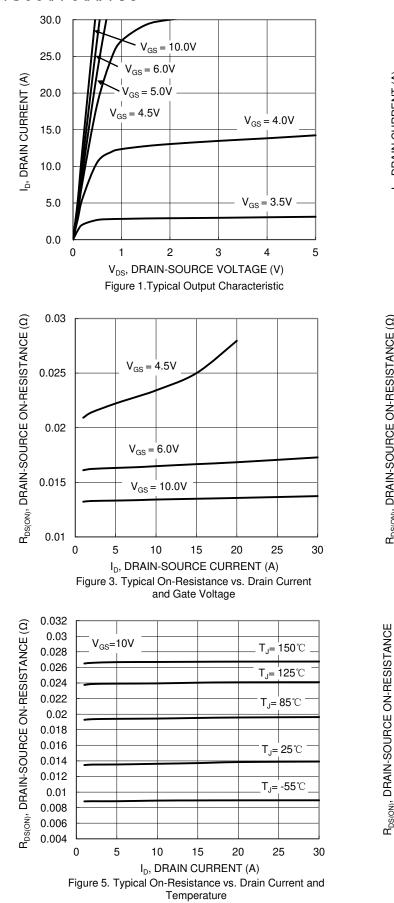
# Electrical Characteristics (@T<sub>c</sub> = +25°C, unless otherwise specified.)

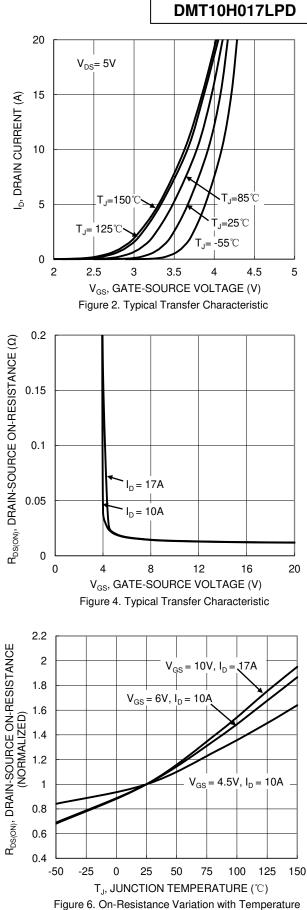
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)			•		•		
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	100	_	_	V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μA	$V_{DS} = 80V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 16V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)	<u>.</u>						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1	—	3	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$	
Static Drain-Source On-Resistance		_	13.7	17.4	mΩ	$V_{GS} = 10V, I_D = 17A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	23.5	30.3	11152	$V_{GS} = 4.5V, I_D = 10A$	
Diode Forward Voltage	V <sub>SD</sub>		0.8	1.3	V	$V_{GS} = 0V, I_{S} = 17A$	
DYNAMIC CHARACTERISTICS (Note 8)			•		•		
Input Capacitance	C <sub>iss</sub>	_	1986	—		$V_{DS} = 50V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss	_	333	—	pF		
Reverse Transfer Capacitance	Crss	_	20	_			
Gate Resistance	R <sub>G</sub>	_	1.17	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	14.4	_			
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	28.6	_	nC	$V_{DS} = 50V, I_D = 20A$	
Gate-Source Charge	Q <sub>gs</sub>	_	5.2	_	no		
Gate-Drain Charge	Q <sub>gd</sub>	_	8.2	_			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	9.8	_		$\label{eq:VDD} \begin{split} V_{DD} &= 50V,  V_{GS} = 10V, \\ R_G &= 11\Omega,  I_D = 20A \end{split}$	
Turn-On Rise Time	t <sub>R</sub>	_	16.3	—	ns		
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	32.6	_	115		
Turn-Off Fall Time	t <sub>F</sub>	_	21.6	—			
Body Diode Reverse Recovery Time	t <sub>RR</sub>	_	40.6	—	ns	I <sub>F</sub> = 17A, di/dt = 100A/µs	
Body Diode Reverse Recovery Charge	Q <sub>RR</sub>	_	58.1	_	nC	I <sub>F</sub> = 17A, di/dt = 100A/µs	

Notes:

Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Thermal resistance from junction to solder point (on the exposed drain pin).
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.

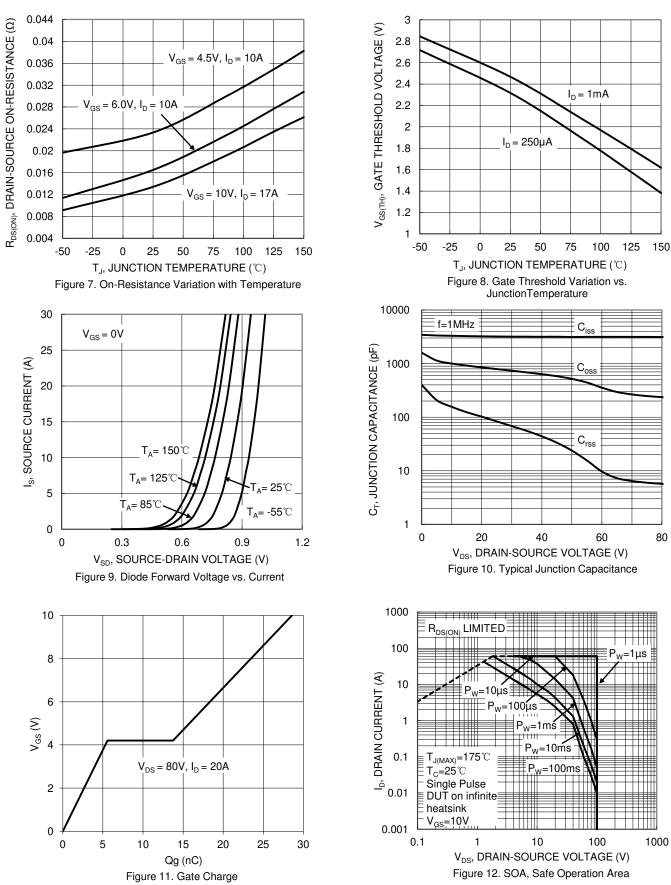




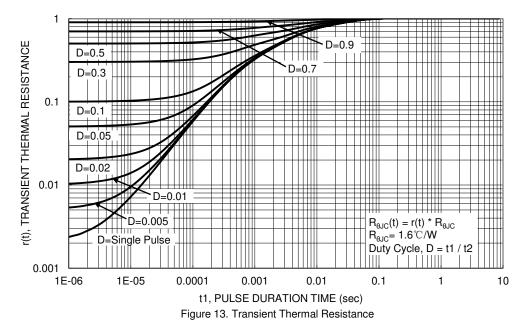




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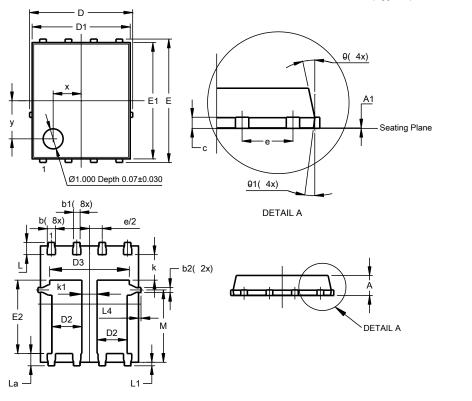






# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



### PowerDI5060-8 (Type E)

#### 0.90 1.10 1.00 Α A1 0 0.05 0.02 0.33 0.51 b 0.41 b1 0.300 0.366 0.333 0.20 0.35 0.25 b2 0.23 0.33 0.277 С D 5.15 BSC 4.85 4.90 D1 4.95 D2 1.40 1.60 1.50 D3 3.98 Е 6.15 BSC E1 5.75 5.85 5.80 E2 3.56 3.76 3.66 е 1.27BSC 1.27 k -k1 0.56 -L 0.51 0.71 0.61 La 0.51 0.71 0.61 0.05 0.20 0.175 L1 L4 0.125 3.50 3.71 Μ 3.605 1.400 X -1.900 v <u>10°</u> 12° 11° θ θ1 7° 6° 8° All Dimensions in mm

PowerDI5060-8

(Type E)

Max

Тур

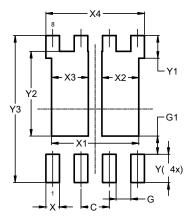
Min

Dim

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### PowerDI5060-8 (Type E)



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	3.910
X2	1.650
X3	1.650
X4	4.420
Y	1.270
Y1	1.020
Y2	3.810
Y3	6.610



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